

Isc N-Channel MOSFET Transistor

IPA65R110CFD

• FEATURES

- With TO-220F package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

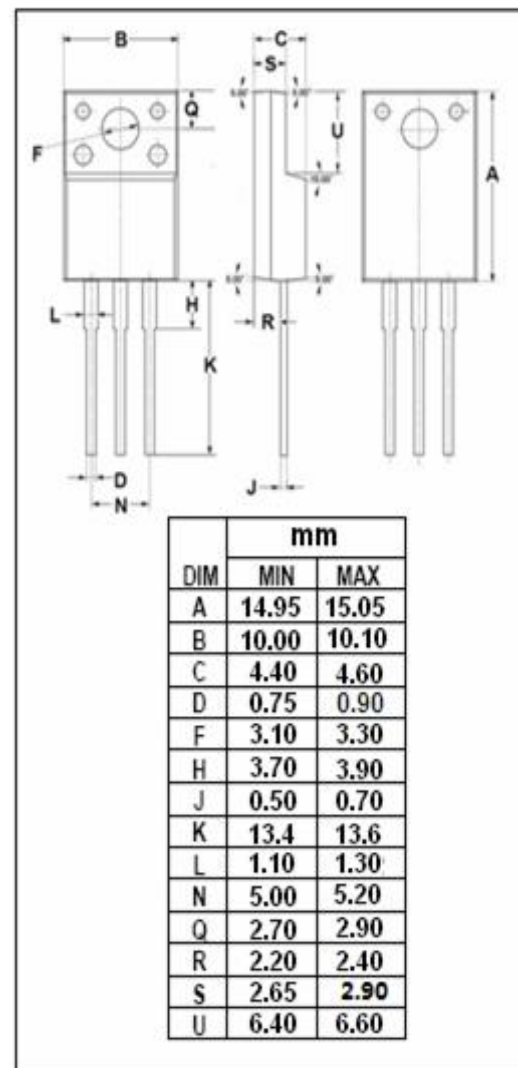
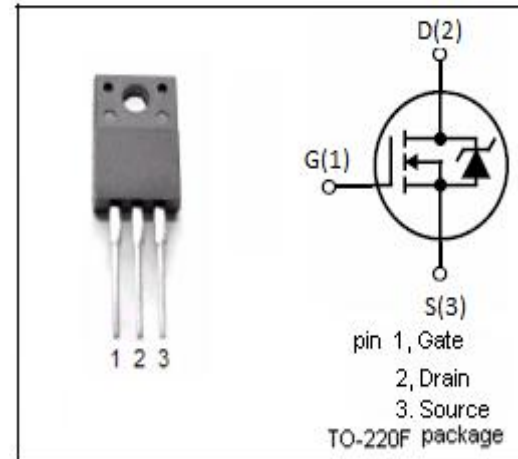
- Switching applications

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous @T _c =25°C T _c =100°C	31.2 19.7	A
I _{DM}	Drain Current-Single Pulsed	99.6	A
P _D	Total Dissipation @T _c =25°C	277.8	W
T _{ch}	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(ch-c)}	Channel-to-case thermal resistance	3.6	°C/W
R _{th(ch-a)}	Channel-to-ambient thermal resistance	80	°C/W



Isc N-Channel MOSFET Transistor**IPA65R110CFD****ELECTRICAL CHARACTERISTICS**T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =1mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = ±20V; I _D =1.3mA	3.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =12.7A		99	110	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V; T _J =25°C V _{DS} = 600V; V _{GS} = 0V; T _J =150°C			1.5 400	μA
V _{SDF}	Diode forward voltage	I _{SD} =19.1A, V _{GS} = 0 V		0.9		V

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